NX3L4684

Low-ohmic dual single-pole double-throw analog switch

Rev. 5 — 7 January 2011

Product data sheet

1. General description

The NX3L4684 is a dual low-ohmic single-pole double-throw analog switch, suitable for use as an analog or digital multiplexer/demultiplexer. Each switch has a digital select input (nS), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ).

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC} . This makes it possible for the NX3L4684 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4684 allows signals with amplitude up to V_{CC} to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ. Its low ON resistance (0.3 Ω for Y0 port, 0.5 Ω for Y1 port) and flatness (0.1 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak) for Y0 port:
 - 0.8 Ω (typical) at $V_{CC} = 1.4 \text{ V}$
 - 0.5 Ω (typical) at V_{CC} = 1.65 V
 - 0.3 Ω (typical) at $V_{CC} = 2.3 \text{ V}$
 - 0.25 Ω (typical) at V_{CC} = 2.7 V
 - 0.25 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 4000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - ◆ IEC61000-4-2 contact discharge exceeds 6000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic dual single-pole double-throw analog switch

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

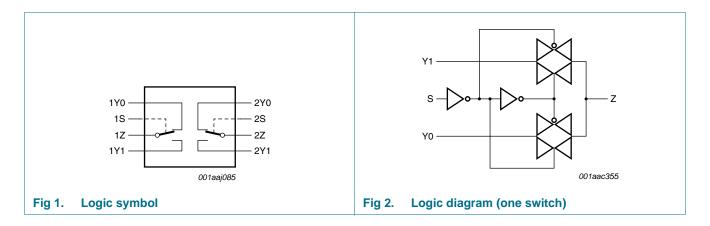
Type number	Package								
	Temperature range	Name	Description	Version					
NX3L4684GM	–40 °C to +125 °C	XQFN10U	plastic extremely thin quad flat package; no leads; 10 terminals; UTLP based; body $2 \times 1.55 \times 0.5$ mm	SOT1049-2					
NX3L4684TK	–40 °C to +125 °C	HVSON10	plastic thermal enhanced very thin small outline package; no leads; 10 terminals; $3 \times 3 \times 0.85$ mm	SOT650-1					

5. Marking

Table 2. Marking

Type number	Marking code
NX3L4684GM	D84
NX3L4684TK	D84

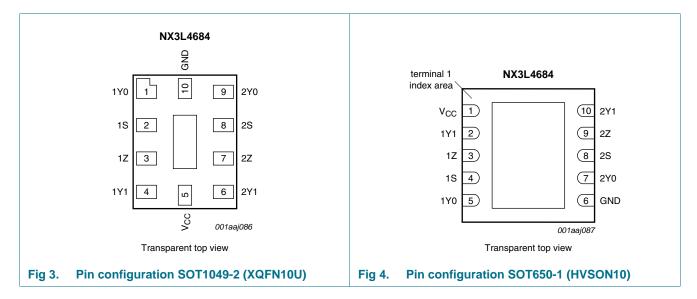
6. Functional diagram



Low-ohmic dual single-pole double-throw analog switch

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT1049-2	SOT650-1	
1Y0	1	5	independent input or output
1S	2	4	select input
1Z	3	3	common output or input
1Y1	4	2	independent input or output
V _{CC}	5	1	supply voltage
2Y1	6	10	independent input or output
2Z	7	9	common output or input
2S	8	8	select input
2Y0	9	7	independent input or output
GND	10	6	ground (0 V)

Low-ohmic dual single-pole double-throw analog switch

8. Functional description

Table 4. Function table[1]

Input nS	Channel on
L	nY0
Н	nY1

^[1] H = HIGH voltage level;L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	select input nS	[<u>1]</u> -0.5	+4.6	V
V_{SW}	switch voltage	switch input nY0 or nY1	[2] -0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mA
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$	[3] _	250	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
V_{I}	input voltage	select input nS	0	4.3	V
V_{SW}	switch voltage	switch input nY0 or nY1	[1] 0	V_{CC}	V
T_{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	[2] _	200	ns/V

^[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

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^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

^[3] For XQFN10U packages: above 132 °C the value of P_{tot} derates linearly with 14.1 mW/K. For HVSON10 packages: above 135 °C the value of P_{tot} derates linearly with 17.2 mW/K.

^[2] Applies to select input nS signal levels.

Low-ohmic dual single-pole double-throw analog switch

11. Static characteristics

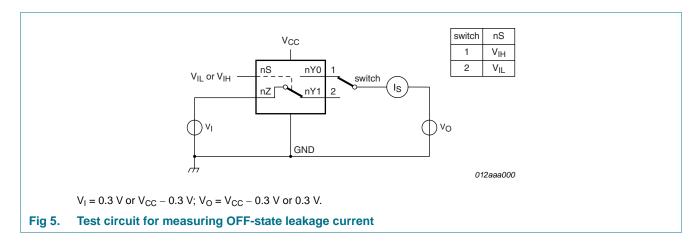
Table 7. Static characteristics

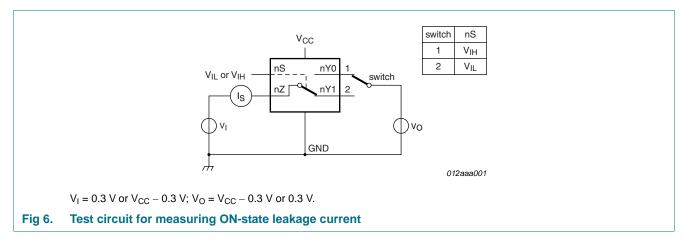
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	Unit		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V_{IH}	HIGH-level	V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V _{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V _{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V_{IL}	LOW-level	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.5	-	0.5	0.4	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
l _l	input leakage current	select input nS; $V_I = GND \text{ to } 4.3 \text{ V};$ $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-	-	-	±0.5	±1	μА
I _{S(OFF)} OFF-state leakage	nYn port; see Figure 5								
	V _{CC} = 1.4 V to 3.6 V	-	-	±5	-	±10	±100	nΑ	
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±200	nΑ
I _{S(ON)}	ON-state	nZ port; see Figure 6							
	leakage	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±20	±200	nΑ
	current	V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±400	nΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 \text{ V}$	-	-	100	-	300	3000	nΑ
		$V_{CC} = 4.3 \text{ V}$	-	-	150	-	500	5000	nΑ
ΔI_{CC}	additional	$V_{SW} = GND \text{ or } V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μΑ
		$V_I = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μΑ
		$V_I = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μΑ
		$V_I = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μΑ
		$V_I = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nΑ
Cı	input capacitance		-	1.0	-	-	-	-	pF
C _{S(OFF)}	OFF-state	port nY0	-	65	-	-	-	-	pF
	capacitance	port nY1	-	35	-	-	-	-	pF
C _{S(ON)}	ON-state	port nY0	-	260	-	-	-	-	pF
	capacitance	port nY1	-	160	-	-	-	-	рF

Low-ohmic dual single-pole double-throw analog switch

11.1 Test circuits





Low-ohmic dual single-pole double-throw analog switch

11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 21.

Symbol	Parameter	Conditions		T _{amb}	= −40 °C °C	to +85		-40 °C to 5 °C	Unit
			Min	Typ[1]	Max	Min	Max		
R _{ON(peak)}	ON resistance (peak)	port nY0; see Figure 7; V _I = GND to V _{CC} ; I _{SW} = 100 mA	,						'
		V _{CC} = 1.4 V		-	0.85	2.0	-	2.2	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.55	8.0	-	0.9	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.35	0.5	-	0.6	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.30	0.45	-	0.5	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.30	0.45	-	0.5	Ω
		port nY1; see Figure 7; $V_I = GND \text{ to } V_{CC}; I_{SW} = 100 \text{ mA}$							
		$V_{CC} = 1.4 \text{ V}$		-	1.65	3.7	-	4.1	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.95	1.6	-	1.7	Ω
	$V_{CC} = 2.3 \text{ V}$		-	0.55	8.0	-	0.9	Ω	
		$V_{CC} = 2.7 \text{ V}$		-	0.50	0.75	-	0.9	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.50	0.75	-	0.9	Ω
∆R _{ON}	ON resistance mismatch between channels	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA	[2]						
		$V_{CC} = 1.4 \text{ V}$		-	0.15	0.3	-	0.3	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.15	0.2	-	0.3	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.04	0.08	-	0.1	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.04	0.075	-	0.1	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.04	0.075	-	0.1	Ω
$R_{ON(flat)}$	ON resistance (flatness)	port nY0; $V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$	[3]						
		V _{CC} = 1.4 V		-	0.5	1.7	-	1.8	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.25	0.6	-	0.7	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.1	0.2	-	0.2	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.1	0.15	-	0.2	Ω
		V _{CC} = 4.3 V		-	0.1	0.20	-	0.25	Ω
		port nY1; V_I = GND to V_{CC} ; I_{SW} = 100 mA	[3]						
		V _{CC} = 1.4 V		-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V		-	0.5	1.2	-	1.3	Ω
		V _{CC} = 2.3 V		-	0.15	0.3	-	0.35	Ω
		V _{CC} = 2.7 V		-	0.13	0.3	-	0.35	Ω
		V _{CC} = 4.3 V		-	0.2	0.4	-	0.45	Ω

^[1] Typical values are measured at T_{amb} = 25 °C.

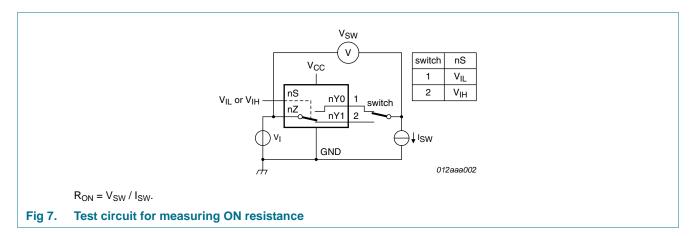
NX3L4684

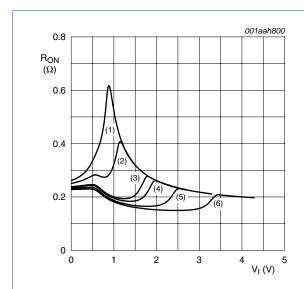
^[2] Measured at identical V_{CC} , temperature and input voltage.

^[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

Low-ohmic dual single-pole double-throw analog switch

11.3 ON resistance test circuit and graphs

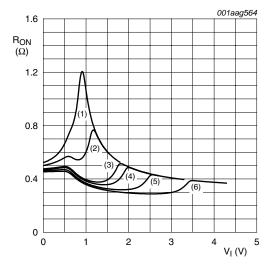




- (1) $V_{CC} = 1.5 \text{ V}.$
- (2) $V_{CC} = 1.8 \text{ V}.$
- (3) $V_{CC} = 2.5 \text{ V}.$
- (4) $V_{CC} = 2.7 \text{ V}.$
- (5) $V_{CC} = 3.3 \text{ V}.$
- (6) $V_{CC} = 4.3 \text{ V}.$

Measured at T_{amb} = 25 °C.

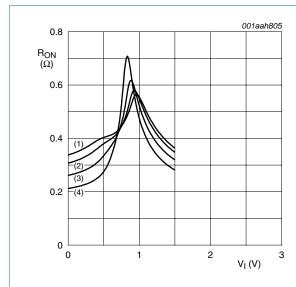
Fig 8. Typical ON resistance as a function of input voltage (nY0 port)



- (1) $V_{CC} = 1.5 \text{ V}.$
- (2) $V_{CC} = 1.8 \text{ V}.$
- (3) $V_{CC} = 2.5 \text{ V}.$
- (4) $V_{CC} = 2.7 \text{ V}.$
- (5) $V_{CC} = 3.3 \text{ V}.$
- (6) $V_{CC} = 4.3 \text{ V}.$

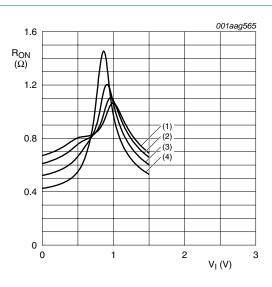
Measured at T_{amb} = 25 °C.

Fig 9. Typical ON resistance as a function of input voltage (nY1 port)



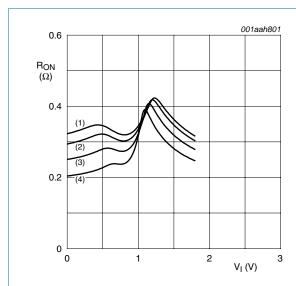
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 10. ON resistance as a function of input voltage; $V_{CC} = 1.5 \text{ V (nY0 port)}$



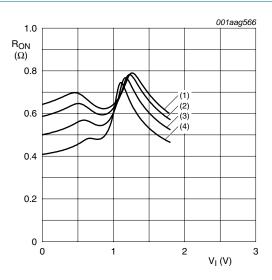
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 11. ON resistance as a function of input voltage; $V_{CC} = 1.5 \text{ V (nY1 port)}$



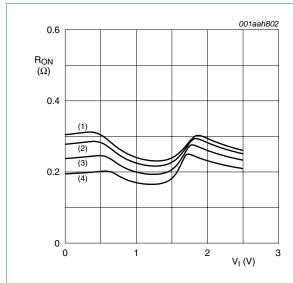
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 12. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V (nY0 port)}$



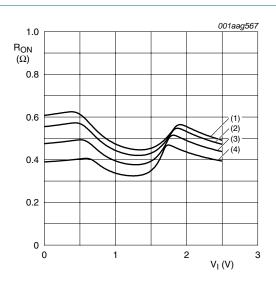
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 13. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V (nY1 port)}$



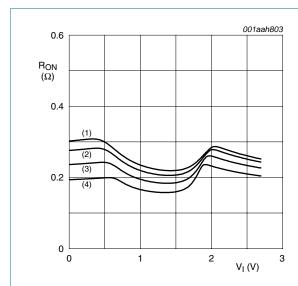
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 14. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V (nY0 port)}$



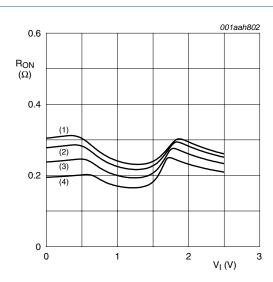
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 15. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V (nY1 port)}$



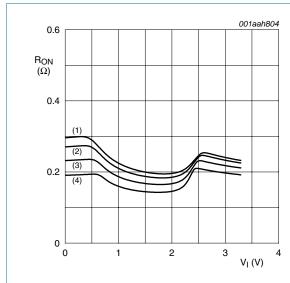
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 16. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V (nY0 port)}$



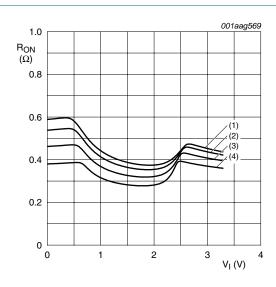
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 17. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V (nY1 port)}$



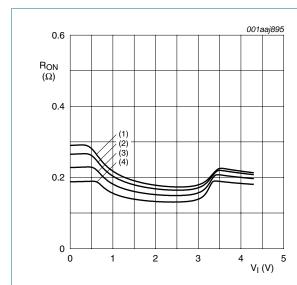
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 18. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V (nY0 port)}$



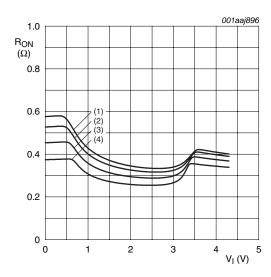
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 19. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V (nY1 port)}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 20. ON resistance as a function of input voltage; $V_{CC} = 4.3 \text{ V (nY0 port)}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 21. ON resistance as a function of input voltage; $V_{CC} = 4.3 \text{ V (nY1 port)}$

Low-ohmic dual single-pole double-throw analog switch

12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 24.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	Unit		
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nS to nZ or nYn; see <u>Figure 22</u>							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	50	100	-	130	130	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	35	80	-	85	95	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	24	50	-	55	60	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	20	45	-	50	55	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	20	45	-	50	55	ns
t _{dis}	disable time	nS to nZ or nYn; see <u>Figure 22</u>							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	30	70	-	80	90	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	18	55	-	60	65	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	11	25	-	30	35	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	9	20	-	25	30	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	9	20	-	25	30	ns
t _{b-m}	break-before-make	see Figure 23	[2]						
	time	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	20	-	9	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	19	-	7	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	13	-	4	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	10	-	2	-	-	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	10	-	1	-	-	ns

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

^[2] Break-before-make guaranteed by design.

Low-ohmic dual single-pole double-throw analog switch

12.1 Waveform and test circuits

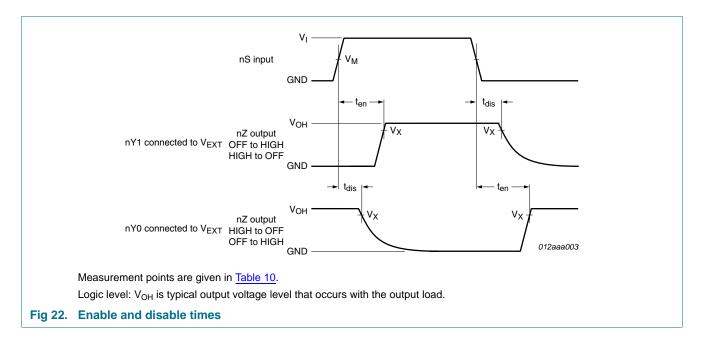
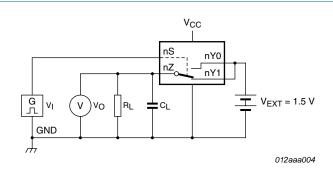


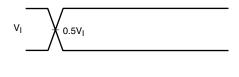
Table 10. Measurement points

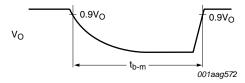
Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

Low-ohmic dual single-pole double-throw analog switch



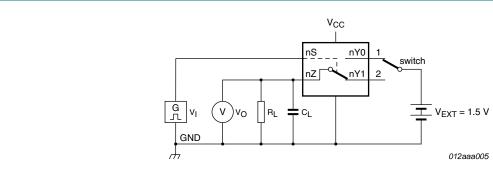
a. Test circuit.





b. Input and output measurement points

Fig 23. Test circuit for measuring break-before-make timing



Test data is given in Table 11.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

Fig 24. Load circuit for switching times

Table 11. Test data

Supply voltage	Input I		Load	
V _{CC}	VI	t _r , t _f	CL	R _L
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω

NX3L4684

Low-ohmic dual single-pole double-throw analog switch

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

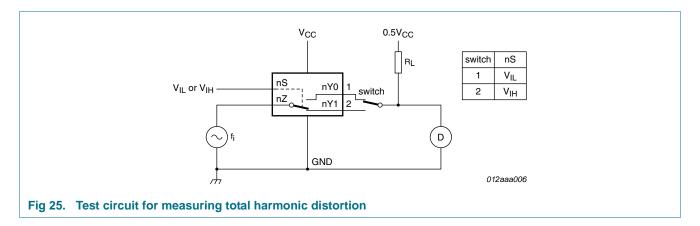
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_l = \text{GND}$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

Symbol	Parameter	Conditions		Ta	_{imb} = 25 °C		Unit
					Тур	Max	
THD	total harmonic	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Figure 25	<u>[1]</u>			'	
	distortion	$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$		-	0.06	-	%
		$V_{CC} = 1.65 \text{ V}; V_I = 1.2 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 2.3 \text{ V}; V_I = 1.5 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; V_{I} = 2 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; V_{I} = 2 \text{ V (p-p)}$		-	0.02	-	%
		V_{CC} = 3.0 V; V_I = 1 V (p-p); R_L = 600 Ω		-	0.01	-	%
f _(-3dB)	-3 dB frequency	$R_L = 50 \Omega$; see Figure 26	<u>[1]</u>				
	response	port nY0; V _{CC} = 1.4 V to 4.3 V		-	15	-	MHz
		port nY1; V _{CC} = 1.4 V to 4.3 V		-	20	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 100 kHz; R_L = 50 Ω ; see Figure 27	<u>[1]</u>				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
V_{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 28					
		V _{CC} = 1.4 V to 3.6 V		-	0.5	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.7	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see Figure 29	<u>[1]</u>				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
Q _{inj}	charge injection	f_i = 1 MHz; C_L = 0.1 nF; R_L = 1 M Ω ; V_{gen} = 0 V; R_{gen} = 0 Ω ; see <u>Figure 30</u>					
		V _{CC} = 1.5 V		-	10	-	рС
		V _{CC} = 1.8 V		-	14	-	рС
		V _{CC} = 2.5 V		-	21	-	рС
		$V_{CC} = 3.3 \text{ V}$		-	30	-	рС
		V _{CC} = 4.3 V		-	50	-	рС

^[1] f_i is biased at $0.5V_{CC}$.

Low-ohmic dual single-pole double-throw analog switch

12.3 Test circuits



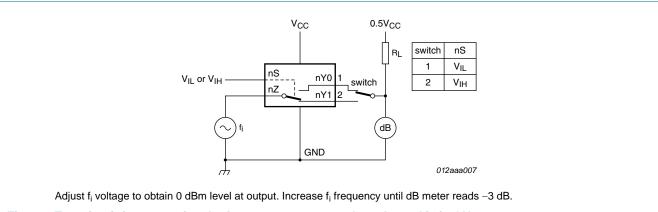
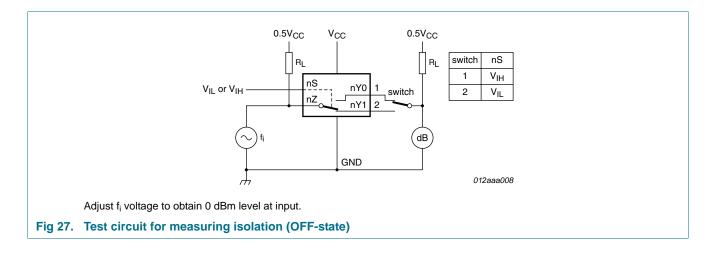
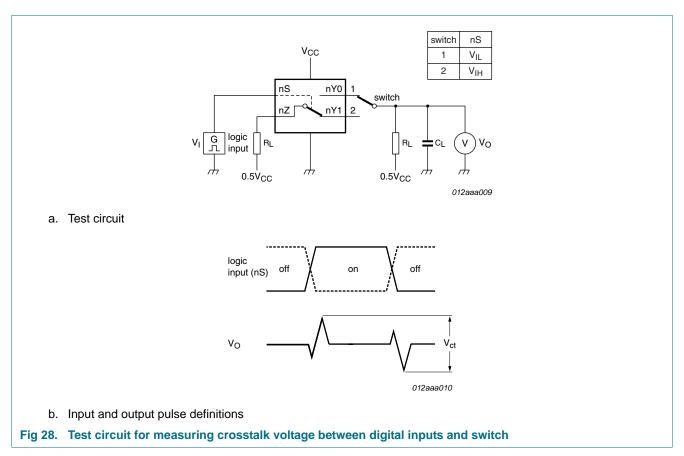
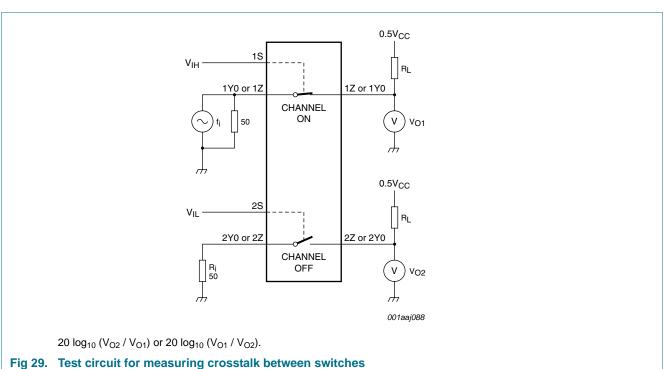


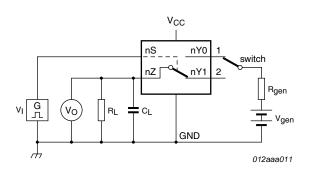
Fig 26. Test circuit for measuring the frequency response when channel is in ON-state



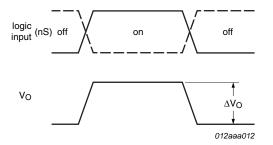




Low-ohmic dual single-pole double-throw analog switch



a. Test circuit.



b. Input and output pulse definitions

Definition: $Q_{inj} = \Delta V_O \times C_L$.

 ΔV_{O} = output voltage variation.

R_{gen} = generator resistance.

 V_{gen} = generator voltage.

Fig 30. Test circuit for measuring charge injection

Low-ohmic dual single-pole double-throw analog switch

13. Package outline

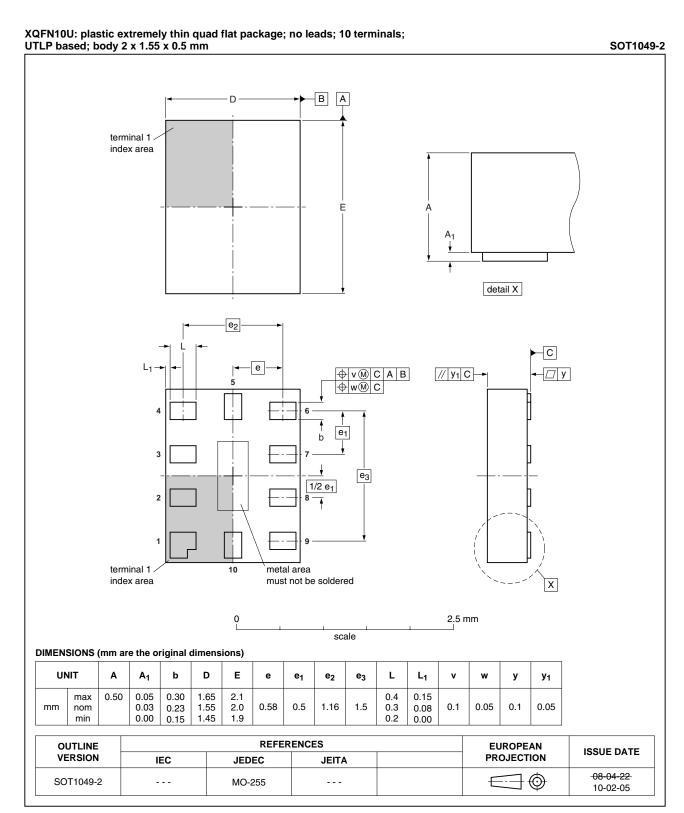


Fig 31. Package outline SOT1049-2 (XQFN10U)

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Low-ohmic dual single-pole double-throw analog switch

HVSON10: plastic thermal enhanced very thin small outline package; no leads; 10 terminals; body $3 \times 3 \times 0.85$ mm

SOT650-1

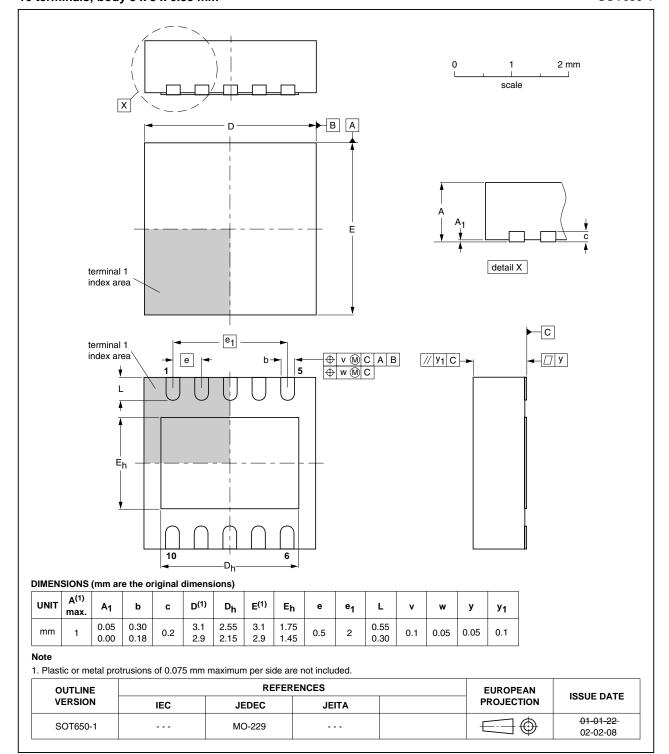


Fig 32. Package outline SOT650-1 (HVSON10)

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Low-ohmic dual single-pole double-throw analog switch

14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant

15. Revision history

Table 14. Revision history

	•				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
NX3L4684 v.5	20110107	Product data sheet	-	NX3L4684 v.4	
Modifications:	• <u>Section 2</u> : IEC61000-4-2 added.				
NX3L4684 v.4	20100324	Product data sheet	-	NX3L4684 v.3	
NX3L4684 v.3	20100209	Product data sheet	-	NX3L4684 v.2	
NX3L4684 v.2	20090401	Product data sheet	-	NX3L4684 v.1	
NX3L4684 v.1	20081127	Product data sheet	-	-	

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16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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18. Contents

1	General description
2	Features and benefits
3	Applications
4	Ordering information
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning
7.2	Pin description
8	Functional description 4
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits
11.2	ON resistance
11.3	ON resistance test circuit and graphs 8
12	Dynamic characteristics
12.1	Waveform and test circuits
12.2	Additional dynamic characteristics 15
12.3	Test circuits
13	Package outline 19
14	Abbreviations
15	Revision history 21
16	Legal information 22
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks23
17	Contact information 23
18	Contents 24

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